











24 SERIES

3.5A HIGH CURRENT ▲ SI MOSFET RELAY

SILICON Si MOSFET RELAY ▲ DIP and SMD type Up to 3500mA ▲ Switches AC or DC load One channel and two channel packages available Input TTL / CMOS compatible

Moisture Sensitivity Level ▲ MSL 1 UL 1577 approved ▲ File no E344988

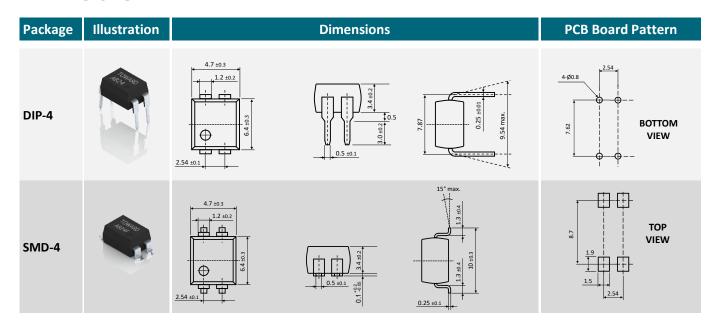
SPECIFICATION

Item		Characteristics
Contact Form		1 Form A / 2 Form A ▲ Normally open switch
Load Voltage	V_L	40V
Operation LED Current	I _{F ON}	3mA
Load Current	I _L	3500mA
On-Resistance	Ron	0.027Ω
Output Capacitance	Соит	810pF
Low Off-State Leakage Current	I _{LEAK}	1μA at 40V _{DC}

APPLICATIONS

Automatic Test	I/O	Industrial	Measurement	Security	Sensing	Telecom
Equipment	Modules	Automation	Equipment	Equipment	Equipment	Equipment
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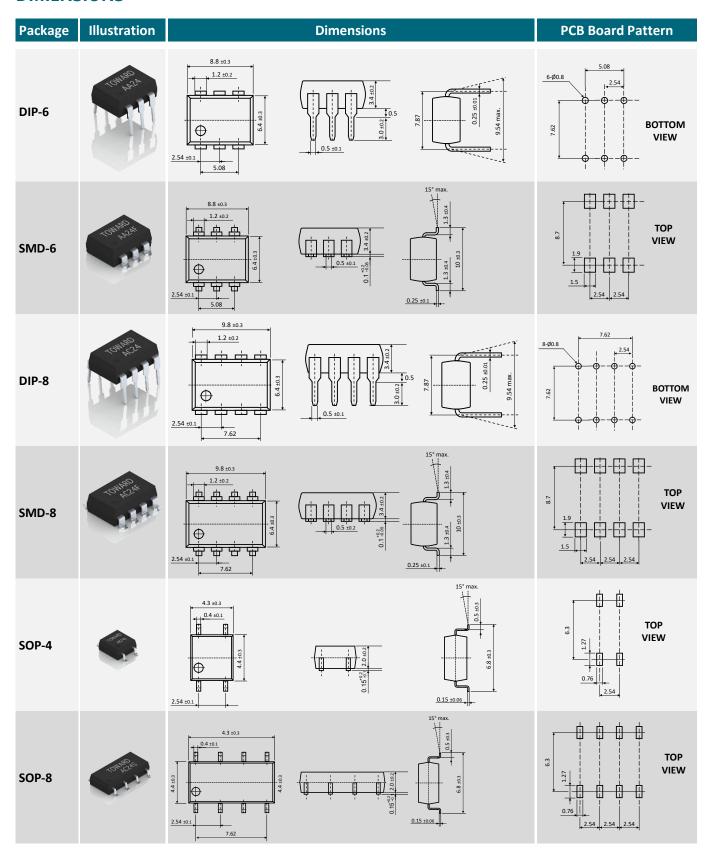
DIMENSIONS



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DIMENSIONS





ABSOLUTE MAXIMUM RATINGS \blacktriangle AMBIENT TEMPERATURE $T_A = 25^{\circ}C$

	ltem	Condition	Symbol			Value		_	Unit
	Outline package			SOP-4	SOP-8	DIP-4 SMD-4	DIP-8 SMD-8	DIP-6 SMD-6	
Type	Part number			AB24S	AC24S	AB24(F)	AC24(F)	AA24(F)	
	Output channels			1	2	1	2	1	Channels
	Continuous LED Current		I _F			50			mA
Immud	Peak LED Current	100 Hz, Duty 1%	I _{FP}			500			mA
Input	LED Reverse Voltage		V_R	5		V			
	Input Power Dissipation		P _{IN}			75			mV
	Load Voltage		V_{L}		40 (AC peak o	r DC)		V
Outrot	Load Current		IL	2500	2000	2500	2000	3500	mA
Output	Peak Load Current	1 ms, 1 shot	I _{PEAK}	6000	6000	6000	6000	8000	mA
	Output Power Dissipation		P _{OUT}	350	450	350	450	500	mW
	Total Power Dissipation		P_{T}	400	500	400	500	550	mW
	I/O Breakdown Voltage		V _{I/O}	1500	1500	3750	3750	3750	V_{RMS}
Relay	I/O Breakdown Voltage (Suffix-H)		$V_{\text{I/O}}$	3750	3750	5000	5000	5000	V_{RMS}
	Operating Temperature Range		T_{OPR}	-40 to +85			°C		
	Storage Temperature Range		T_{STG}		-	40 to +10	0		°C

ELECTRICAL CHARACTERISTICS ▲ **AMBIENT TEMPERATURE** T_A = 25°C

	Item	Condition	Symbol	Min.	Тур.	Max.	Unit
	LED Forward Voltage	I _F = 10mA	V_{F}	1	1.37	1.5	V
Input	Operation LED Current		I _{F ON}		0.5 (SOP) 1.2 (DIP)	3	mA
	Recovery LED Voltage		$V_{\text{F OFF}}$	0.5	1.2		V
	On-Resistance				0.033	0.043	
	Drain to Drain (tested within 1 sec.)	I _F =5mA, I _L =Rating	R _{ON}		0.027 (DIP6)	0.035 (DIP6)	Ω
Output	Off-State Leakage Current	V _L = 40V	I _{LEAK}			1	μΑ
	Output Capacitance	V _L =0V, f=1MHz	C _{OUT}		240 810 (DIP6)		pF
Turne	Turn-On Time (for SOP4,8 type) Turn-On Time (for DIP4,8 type)	I _F =5mA, I _L =Rating	t _{on}		0.8 1.2	3	ms
Trans- mission	Turn-Off Time (for SOP/DIP4,8 type)	I _F =5mA, I _L =Rating	t _{OFF}		0.05	0.5	ms
1111331011	Turn-On Time (for DIP6 type)	I _F =10mA, I _L =Rating	t _{ON}		1.2	3	ms
	Turn-Off Time (for DIP6 type)	I _F =10mA, I _L =Rating	t _{OFF}		0.05	0.5	ms
Coupled	I/O Insulation Resistance		R _{I/O}	10 ⁹			Ω
Coupled	I/O Capacitance	f=1MHz	C _{I/O}		1.3		pF

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REFERENCE DATA



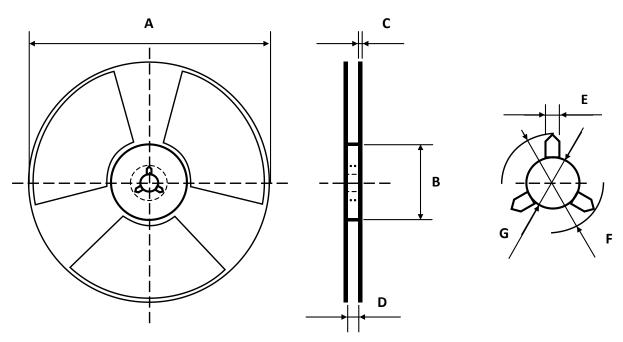


PIN DESCRIPTION AND PART NUMBER

Circuit Diagram	Pin	Description	Part No.	Package	Packing
1 2	1 2 3,4	Anode (+) • LED Cathode (-) • LED Drain • MOSFET	AB24 AB24F AB24S AB24F-R1 AB24S-R1	DIP-4 SMD-4 SOP-4 SMD-4 SOP-4	Tube (90pcs) Tube (90pcs) Tube (100pcs) Reel (1000pcs) Reel (1000pcs)
1 2 3	1 2 3 4,6 5	Anode (+) • LED Cathode (-) • LED NC Drain • MOSFET Source • MOSFET	AA24 AA24F AA24F-R1	DIP-6 SMD-6 SMD-6	Tube (50pcs) Tube (50pcs) Reel (1000pcs)
1 2 3 4	1,3 2,4 5,6,7,8	Anode (+) • LED Cathode (-) • LED Drain • MOSFET	AC24 AC24F AC24S AC24F-R1 AC24S-R1	DIP-8 SMD-8 SOP-8 SMD-8 SOP-8	Tube (45pcs) Tube (45pcs) Tube (50pcs) Reel (1000pcs) Reel (1000pcs)

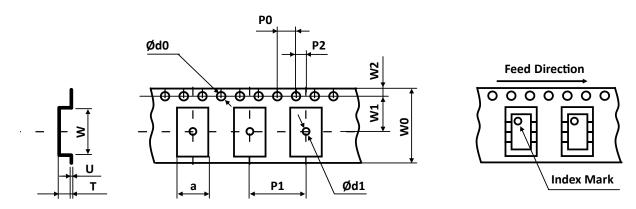


REEL DIMENSIONS ▲ All dimensions in mm



Size	А	В	С	D	Е	F	G
SOP-4	330	100	2	13	2	13	21
SOP-8	330	100	2	17	2	13	21
SMD-4	380	80	2.2	17	2	13	21
SMD-6	380	80	2.2	17	2	13	21
SMD-8	380	80	2.2	17	2	13	21

TAPE DIMENSIONS ▲ All dimensions in mm



Size	w	U	T	а	Ød0	Ød1	P0	P1	P2	W0	W1	W2
SOP-4	4.6	0.3	2.3	7.2	1.5	1.5	4	12	2	12	7.5	1.75
SOP-8	10.4	0.3	2.3	7.5	1.5	1.5	4	12	2	16	7.5	1.75
SMD-4	5.3	0.3	4	10.6	1.5	1.5	4	16	2	16	7.5	1.75
SMD-6	9.15	0.3	4.45	10.4	1.5	1.5	4	16	2	16	11.5	1.75
SMD-8	9.9	0.3	4	10.6	1.5	1.5	4	16	2	16	7.5	1.75

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PACKING QUANTITIES

Tape and Reel Packing	PCS/Reel
SMD-4	1000
SMD-6	1000
SMD-8	1000
SOP-4	1000
SOP-8	1000

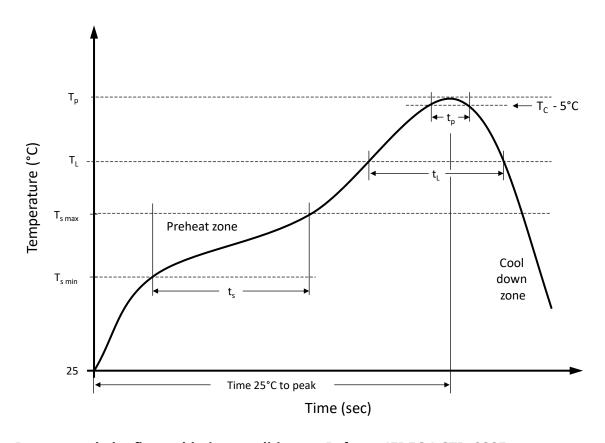
Tube Packing	PCS/Tube	Tubes/Box	Units/Box
DIP-4	90	30	2700
DIP-6	50	30	1500
DIP-8	45	30	1350
SMD-4	90	30	2700
SMD-6	50	30	1500
SMD-8	45	30	1350
SOP-4	100	30	3 000
SOP-8	50	30	1500

STORAGE AND HANDLING CONDITIONS

ESD level	Floor life	Conditions	MSL
HBM class 2	Unlimited	T _A < 30°C, RH < 85%	1



RECOMMENDED REFLOW SOLDERING PROFILE A SMD PACKAGE

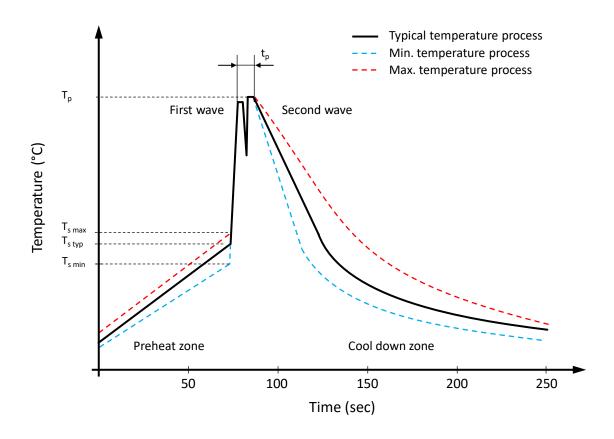


Recommended reflow soldering conditions ▲ **Refer to JEDEC J-STD-020E**

Profile Features		Sn-Pb Eutetic Assembly	Pb-Free Assembly
Preheat temperature min.	$T_{s min}$	100 °C	150 °C
Preheat temperature max.	T _{s max}	150 °C	200 °C
Preheat time t _s from T _{s min} to T _{s max}	t_s	120 seconds	120 seconds
Ramp-up rate (T _L to T _p)		max. 3 °C/second	max. 3 °C/second
Liquidous temperature	T_L	183 °C	217 °C
Time t _L maintained above T _L	t _L	150 seconds max.	60 seconds max.
Peak package body temperature	T_p	235°C	260°C
Timeframe of within 5°C below and up to max actual peak body temperature	t _p	20 seconds max.	30 seconds max.
Ramp-down rate (T _L to T _p)		max. 6 °C/second	max. 6 °C/second
Time 25°C to peak temperature		max. 6 minutes	max. 8 minutes



RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE



Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

Profile Features		Value ▲ Sn-Pb Assembly	Value ▲ Pb-free Assembly
Preheat temperature min.	T_{smin}	100 °C	100 °C
Preheat temperature typical	T _{s typ}	120 °C	120 °C
Preheat temperature max.	$T_{s max}$	130 °C	130 °C
Preheat time t_s from T_{smin} to T_{smax}	ts	70 seconds	70 seconds
Peak temperature	T_p	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	t _p	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down date min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second
Time 25°C to 25°C		4 minutes	4 minutes



LOAD CONNECTING METHOD

Туре		Load	Connection	Feature
4 pins		AC or DC	V _L (AC or DC)	Control bi-directional signal
	Α	AC or DC	V _L (AC or DC)	Control bi-directional signal
6 pins	В	DC	V _L (DC)	On-resistance is 1/2 of A-connection
			I _F V _L (DC)	2-Make-contacts (Source Common)
	С	DC	V _L (DC)	On-Resistance is 1/2 of B-connection
	AC or DC		I _{F1} Load V _L (AC or DC) V _L (AC or DC)	2 input and 2 output
8 pins			Load V _L (AC or DC) V _L (AC or DC)	1 input and 2 output



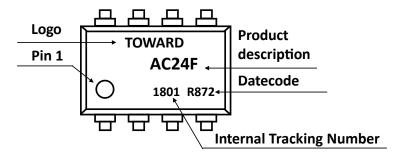
PRODUCT CODE

Example: AC24F series ▲ 2 Form A ▲ 40V ▲ SMD-8 ▲ Tape & Reel

AC		24		-		F		R1	
Package		Sei	ries	s Special Suff		Туре		Packing	
AA AB AC	AB 4 Pin ▲ 1 Form A 24 40V		Blank Standard H High Insulation		Blank F S	DIP SMD SOP	Blank R1	Tube Reel	

PRODUCT MARKING

Example: AC24F series ▲ 2 Form A ▲ 40V ▲ SMD-8 ▲ Tape & Reel



DATE CODE

Example: R872

	R		3	7	7	7	2
Material (Characteristics	Year		Month		Week of the Month	
R	RoHS compliant	8 9 A B	2018 2019 2020 2021	1 2 3 4	Jan Feb Mar Apr	1 2	1 st 2 nd
н	Halogen free	C G	2022 2026	5 12	May Dec	3 4	3 rd 4 th



RELIABILITY TESTS **A** STANDARD

Standard: JESD22-A

No.	Test	Test	Test	Test
1	Moisture Sensitivity Level Test	Specification Bake condition: Temperature: 125°C; Duration 24 hours Soak condition: Temperature: 30°C; Humidity: 60% RH Duration 192 hours Reflow condition: Peak temperature: 260°C Duration: 3 cycles	Standard JESD22-A113H	No abnormal phenomenon was found. Functional test passed.
2	High Temperature Storage Test	Temperature: 150°C Duration: 500 hours	JESD22-A103E	No abnormal phenomenon was found. Functional test passed.
3	Temperature range: -55°C to +125°C Temperature -55°C for 30 minutes Cycling Test +125°C for 30 minutes Duration: 100 cycles with 1 cycle = 70 minutes		JESD22-A104E	No abnormal phenomenon was found. Functional test passed.
4	Low Temperature Storage Test	· · · · · · · · · · · · · · · · · · ·		No abnormal phenomenon was found. Functional test passed.
5	Temperature & Humidity Storage Test	Temperature: 85°C Humidity: 85% RH Duration: 500 hours	JESD22-A101D	No abnormal phenome- non was found. Functional test passed.
6	Highly Accelerated Temperature and Humidity Stress Test	Temperature: 130°C Humidity: 85% RH Duration: 96 hours	JESD22-A-118B	No abnormal phenomenon was found. Functional test passed.



REVISION TABLE

Revision	Date	Status	Notes
001	01/10/2021	Initial release	Initial publication

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